NSN 5961-01-015-1830

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View Online at https://aerobasegroup.com/nsn/5961-01-015-1830 **Inclosure Material:** Metal **Overall Length:** 0.106 inches **Overall Diameter:** 0.189 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, collector-to-base, emitter open and 15.0 breakdown voltage, collector-to-emitter, base open and 2.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 25.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0